

February 2000

LM185/LM285/LM385 Adjustable Micropower Voltage References

General Description

The LM185/LM285/LM385 are micropower 3-terminal adjustable band-gap voltage reference diodes. Operating from 1.24 to 5.3V and over a 10µA to 20mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185 band-gap reference uses only transistors and resistors, low noise and good long-term stability result.

Careful design of the LM185 has made the device tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose

analog circuitry with battery life approaching shelf life. Further, the wide operating current allows it to replace older references with a tighter tolerance part.

The LM185 is rated for operation over a -55°C to 125°C temperature range, while the LM285 is rated -40°C to 85°C and the LM385 0°C to 70°C. The LM185 is available in a hermetic TO-46 package and a leadless chip carrier package, while the LM285/LM385 are available in a low-cost TO-92 molded package, as well as S.O.

Features

- Adjustable from 1.24V to 5.30V
- Operating current of 10µA to 20mA
- 1% and 2% initial tolerance
- 1Ω dynamic impedance
- Low temperature coefficient

Connection Diagrams

TO-92 Plastic Package



Bottom View

Metal Can Package

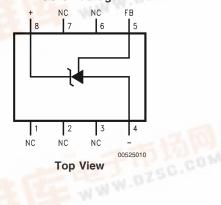


TO-46

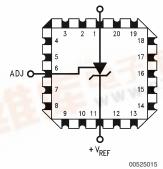
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Bottom View

SOIC Package



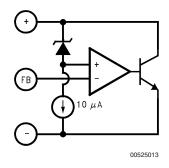
20-Leadless Chip Carrier



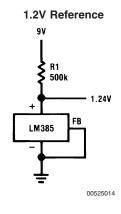
Top View

Package	Temperature Range							
	-55°C to 125°C	–40°C to 85°C	0°C to 70°C	Drawing				
	LM185BH							
TO 40	LM185BH/883			110011				
TO-46	LM185BYH			H03H				
	LM185BYH/883							
		LM285BXZ	LM385BXZ					
TO-92		LM285BYZ	LM385BYZ	7004				
10-92		LM285Z	LM385BZ	Z03A				
			LM385Z					
8-Pin SOIC		LM285M	LM385M	MOCA				
0-1111 3010		LM285BYM	LM385BM	M08A				
20-Leadless Chip Carrier	LM185BE/883			E20A				

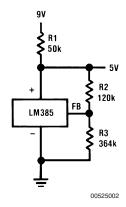
Block Diagram



Typical Applications



5.0V Reference



$$V_{OUT} = 1.24 \left(\frac{R3}{R2} + 1\right)$$

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

(Note 2)

Reverse Current 30mA Forward Current 10mA

Operating Temperature Range (Note 3)

 LM185 Series
 −55°C to 125°C

 LM285 Series
 −40°C to 85°C

 LM385 Series
 0°C to 70°C

Storage Temperature -55°C to 150°C

Soldering Information

TO-92 Package (10 sec.) 260°C TO-46 Package (10 sec.) 300°C

SO Package

 Vapor Phase (60 sec.)
 215°C

 Infrared (15 sec.)
 220°C

See An-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Electrical Characteristics (Note 4)

				M185, LN	/1285		LM385					
Parameter	Conditions	Тур	LM185BX, LM185BY LM185B, LM285BX, LM285BY		LM285		Тур	LM385BX,		LM385		Units (Limit)
			Tested	Design	Tested	Design		Tested	Design	Tested	Design	1
			Limit (Note	Limit (Note	Limit (Note	Limit (Note		Limit (Note	Limit (Note	Limit (Note	Limit (Note	
			5)	6)	5)	6)		5)	6)	5)	6)	
Reference Voltage	I _R = 100μA	1.240	1.252		1.265	1.270	1.240	1.252	1.255	1.265	1.270	V
			1.255 1.228		1.215	1.205		1.228	1.215	1.215	1.205	(max)
			1.215									(min)
Reference Voltage	I _{MIN} < I _R < 1mA	0.2	1	1.5	1	1.5	0.2	1	1.5	1	1.5	mV
Change with Current	1mA < I _R < 20mA	4	10	20	10	20	5	15	25	15	25	(max)
Dynamic Output	$I_R = 100 \mu A, f = 100 Hz$											
Impedance	$I_{AC} = 0.1 I_{R} V_{OUT} = V_{REF}$	0.3					0.4					Ω
	V _{OUT} = 5.3V	0.7					1					
Reference Voltage	I _R = 100μA											mV
Change with Output Voltage		1	3	6	3	6	2	5	10	5	10	(max)
Feedback Current		13	20	25	20	25	16	30	35	30	35	nA (max)
Minimum Operating	V _{OUT} = V _{REF}	6	9	10	9	10	7	11	13	11	13	μА
Current (see curve)	V _{OUT} = 5.3V	30	45	50	45	50	35	55	60	55	60	(max)
Output Wideband	I _R = 100μA, 10Hz < f < 10kHz											
Noise	$V_{OUT} = V_{REF}$ $V_{OUT} = 5.3V$	50 170					50 170					μV _{rms}

Electrical Characteristics (Note 4) (Continued)

		LM185, LM285										
	Conditions		LM185BX, LM185BY LM185B, LM285BX, LM285BY		LM285		Тур	LM385BX,		LM385		
Parameter												Units (Limit)
		Тур										
			Tested	Design	Tested	Design		Tested	Design	Tested	Design	
			Limit	Limit	Limit	Limit		Limit	Limit	Limit	Limit	
			(Note	(Note	(Note	(Note		(Note	(Note	(Note	(Note	
			5)	6)	5)	6)		5)	6)	5)	6)	
Average	I _R = 100μA X Suffix		30					30				ppm/°c
Temperature												
Coefficient	Y Suffix		50					50				(max)
(Note 7)												
	All Others			150		150			150		150	
Long Term	$I_R = 100 \mu A, T = 1000$	20					20					ppm
Stability	Hr,											
	$T_A = 25^{\circ}C \pm 0.1^{\circ}C$											

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H for military specifications.

Note 3: For elevated temperature operation, T_Jmax is:

LM185 150°C LM285 125°C LM385 100°C

Thermal Resistance	TO-92	TO-46	SO-8		
θ_{JA} (Junction to Ambient)	180°C/W (0.4" leads)	440°C/W	165°C/W		
	170°C/W (0.125" leads)				
θ_{JC} (Junction to Case)	N/A	80°C/W	N/A		

Note 4: Parameters identified with boldface type apply at temperature extremes. All other numbers apply at $T_A = T_J = 25^{\circ}C$. Unless otherwise specified, all parameters apply for $V_{REF} < V_{OUT} < 5.3V$.

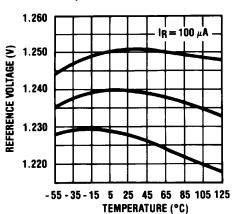
Note 5: Guaranteed and 100% production tested.

Note 6: Guaranteed, but not 100% production tested. These limits are not to be used to calculate average outgoing quality levels.

Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures from T_{MIN} to T_{MAX} , divided by $T_{MAX} - T_{MIN}$. The measured temperatures are -55, -40, 0, 25, 70, 85, 125°C.

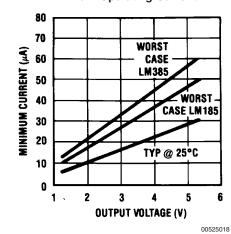
Typical Performance Characteristics

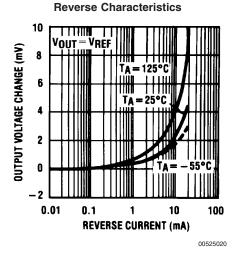




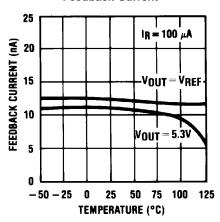
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Minimum Operating Current



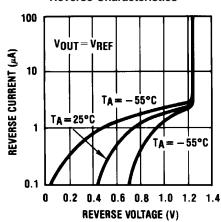


Feedback Current



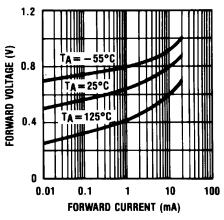
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Reverse Characteristics



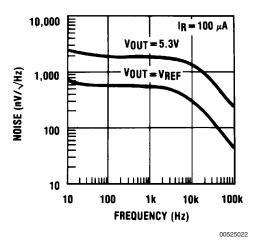
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Forward Characteristics

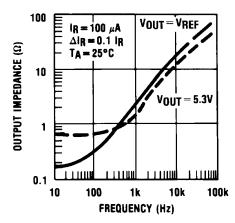


Typical Performance Characteristics (Continued)

Output Noise Voltage

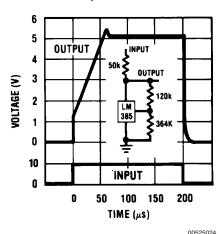


Dynamic Output Impedance

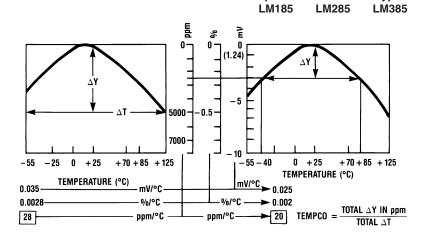


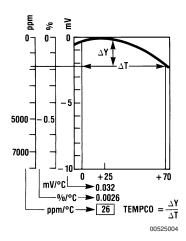
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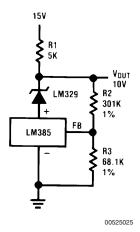
Temperature Coefficient Typical



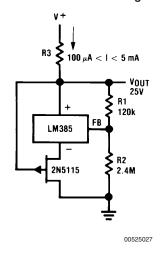


Typical Applications

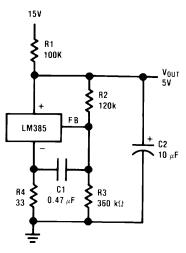
Precision 10V Reference



25V Low Current Shunt Regulator

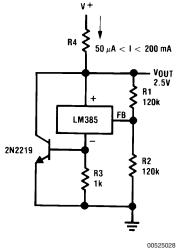


Low AC Noise Reference



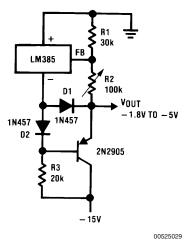
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200 mA Shunt Regulator

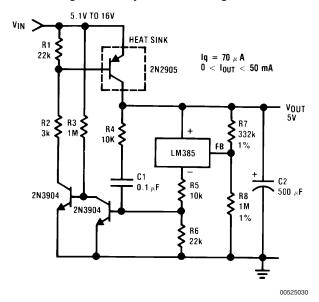


Typical Applications (Continued)

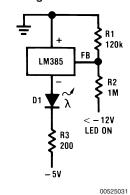
Series-Shunt 20 mA Regulator



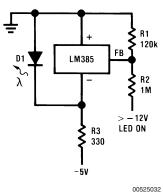
High Efficiency Low Power Regulator



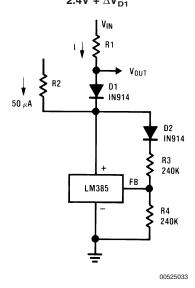
Voltage Level Detector



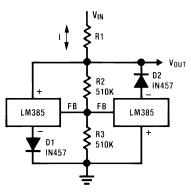
Voltage Level Detector



Fast Positive Clamp 2.4V + Δ V_{D1}

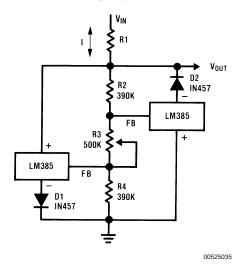


Bidirectional Clamp ±2.4V

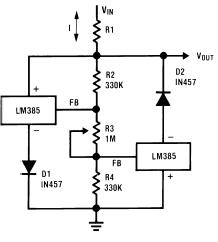


Typical Applications (Continued)

Bidirectional Adjustable Clamp ±1.8V to ±2.4V

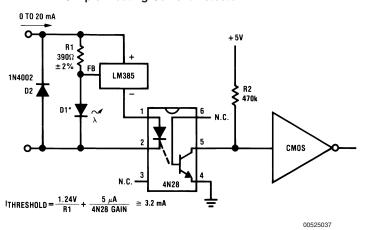


Bidirectional Adjustable Clamp ±2.4V to ±6V

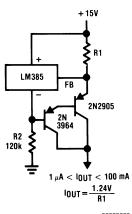


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Simple Floating Current Detector

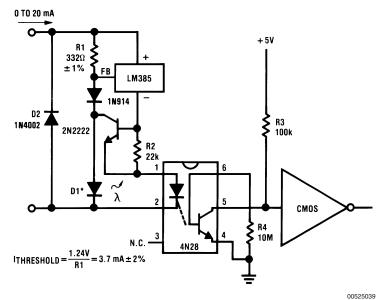


Current Source



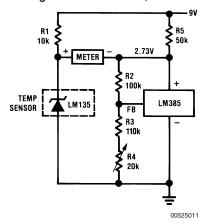
Typical Applications (Continued)

Precision Floating Current Detector



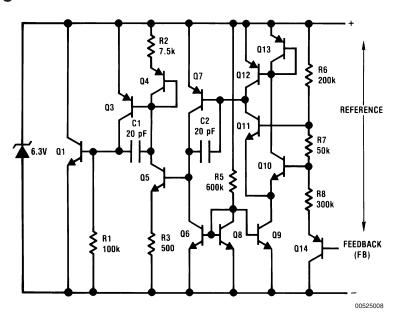
*D1 can be any LED, V_F=1.5V to 2.2V at 3 mA. D1 may act as an indicator. D1 will be on if I_{THRESHOLD} falls below the threshold current, except with I=O.

Centigrade Thermometer, 10mV/°C



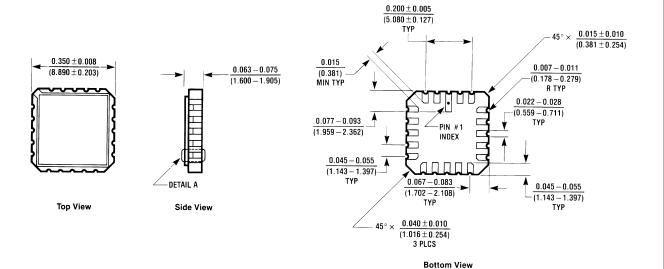
Freezer Alarm R1 100k R2 180k HALLORY SONALERT SNP-428 LM385 LM385 LM385 LM385 LM385 LM385 LM385 LM385 LM385 R4 C2 2.2k 0.033 µF 2M2222 R5 12k D0525012

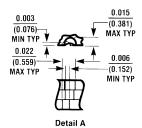
Schematic Diagram



Physical Dimensions inches (millimeters)

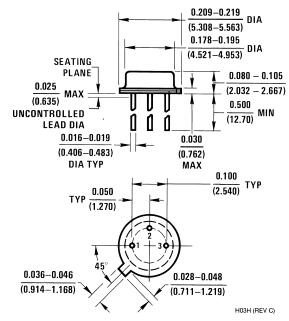
unless otherwise noted





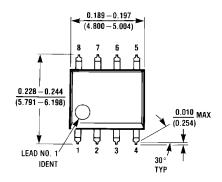
E20A (REV D)

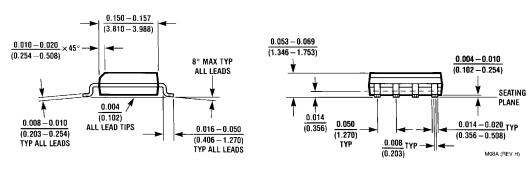
20-Leadless Chip Carrier (E) NS Package Number E20A



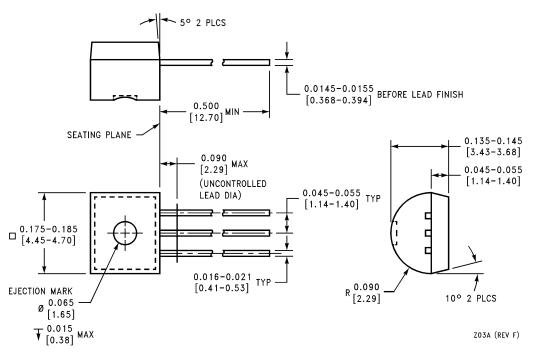
TO-46 Metal Can Package (H) NS Package Number H03H

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





SO Package (M)
NS Package Number M08A



TO-92 Plastic Package (Z) NS Package Number Z03A

Notes

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